

20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

20 V

Current

6.5A

Features

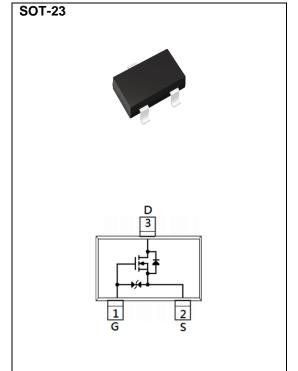
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@6.5A<22m\Omega$
- $R_{DS(ON)}$, $V_{GS}@2.5V$, $I_D@5.5A<26m\Omega$
- R_{DS(ON)}, V_{GS}@1.8V, I_D@5.0A<34m Ω
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _G s	<u>±</u> 8		
Continuous Drain Current(Note 4)		ID	6.5	A	
Pulsed Drain Current(Note 1)		I _{DM}	32		
Power Dissipation	T _a =25°C)	1.25	W	
	Derate above 25°C	P_D	10	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 3,4)		R _θ ЈА	100	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	- V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.4	0.58	1	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =6.5A	-	18.4	22		
		V _{GS} =2.5V, I _D =5.5A	-	21.5	26	mΩ	
		V _{GS} =1.8V, I _D =5A	-	26.4	34		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	Igss	V _{GS} =±8V, V _{DS} =0V	-	-	±10		
Dynamic ^(Note 5)							
Total Gate Charge	Qg		-	8.6	-	nC	
Gate-Source Charge	Q _{gs}	V_{DS} =10V, I_{D} =6.5A, V_{GS} =4.5V ^(Note 2)	-	1.06	-		
Gate-Drain Charge	Q_{gd}	VGS=4.5 V (100 = 7	-	1.04	-		
Input Capacitance	Ciss	\/ 40\/ \/ 0\/	-	836	-	pF	
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V, f=1MHZ	-	96	-		
Reverse Transfer Capacitance	Crss	I=TIVITIZ	-	80	-		
Turn-On Delay Time	td _(on)	101/1	-	24	-	20	
Turn-On Rise Time	tr	V _{DD} =10V, I _D =1A,	-	46	-	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=4.5V$, $R_{G}=3\Omega^{(Note 2)}$	-	0.22	-		
Turn-Off Fall Time	tf	NG-312	-	0.30	-	us	
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	1.5	А	
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.74	1	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

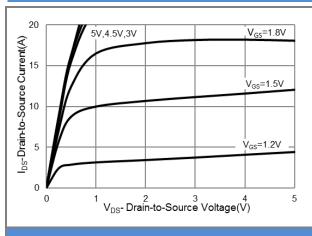


Fig.1 On-Region Characteristics

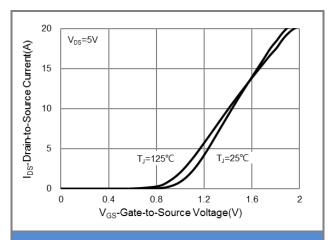


Fig.2 Transfer Characteristics

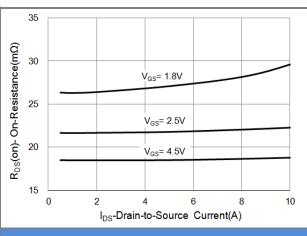


Fig.3 On-Resistance vs. Drain Current

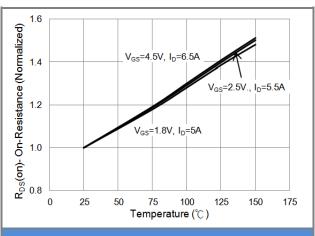
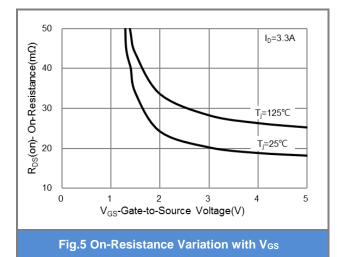
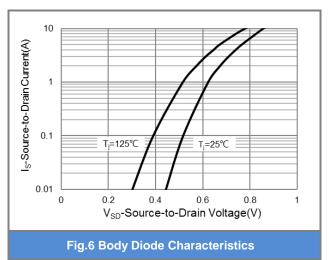


Fig.4 On-Resistance vs. Junction temperature







TYPICAL CHARACTERISTIC CURVES

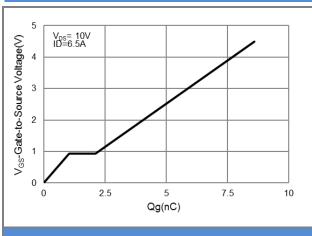


Fig.7 Gate-Charge Characteristics

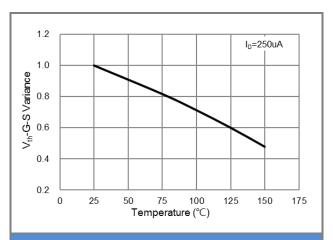


Fig.8 Threshold Voltage Variation with Temperature

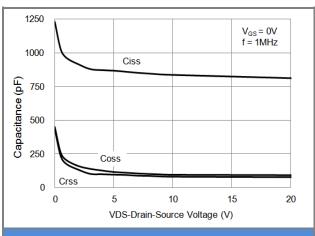


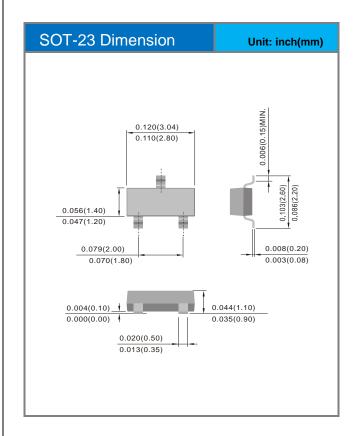
Fig.9 Capacitance vs. Drain-Source Voltage

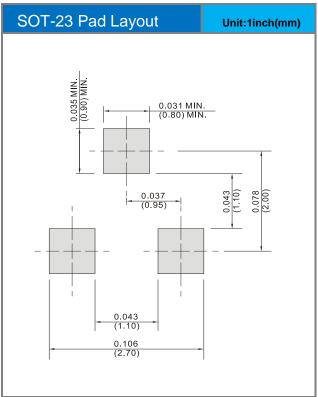


Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3416AE-AU	SOT-23	3K pcs / 7" reel	A6E	

Packaging Information & Mounting Pad Layout







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